

AS1713

Difference Amplifier, 10MHz, 10V/µs, Rail-to-Rail I/O with Shutdown

1 General Description

The AS1713 is a low cost cmos difference amplifier providing extended common mode voltage range for a single rail 5V supply. Resistor trimming during final test ensures a typical common mode rejection of 60dB. Low input bias currents, 10MHz gain bandwidth, low total harmonic distortion (THD) and a rail-to-rail output drive capability of typically 200mA (@ 5V supply) provide support for a number of signal processing applications such as audio line receivers, ground loop breakers and current sensing. Linearity is suitable for 12bit ADC measurement.

A classical single amplifier approach ensures that the differential gain is determined by a simple ratio of two internal resistors. A fixed gain of x1 is available.

Single ended input resistance is equalised (10k Ω ±20%) at each input terminal. This feature provides additional common mode rejection when long balanced input cables connect at the input.

A EN pin reduces the quiescent current of the device.

2 Key Features

Constant Output Drive Capability: 50mA

Rail-to-Rail Input and Output

Supply Current: 1.6mA

Single-Supply Operation: 2.7 to 5.5V

Voltage Gain: 1

Gain-Bandwidth Product: 10MHz

High Slew Rate: 10V/µs

Power-Supply Rejection Ratio: 70dB

Common Mode Rejection Ratio: 60dB

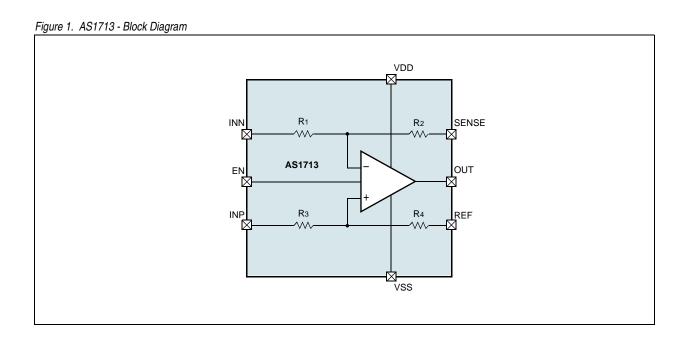
No Phase Reversal for Overdriven Inputs

Unity-Gain Stable for Capacitive Loads: Up to 100pF

Shutdown Mode Current: 1nA MLPD (2x2mm) 8-pin package

3 Applications

The device is ideal for headphone amplifiers with ground interference rejection, infotainment high drive audio line buffers with ground interference rejection, audio differential-to-single-ended conversion and instrumentation amplifier back-end.

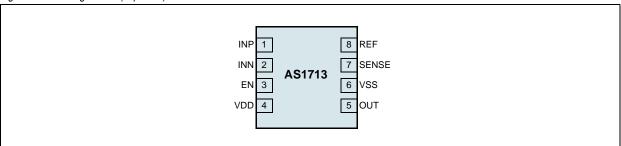




4 Pinout

Pin Assignments

Figure 2. Pin Assignments (Top View)



Pin Descriptions

Table 1. Pin Descriptions

Pin Number	Pin Name	Description
1	INP	Non-inverting Input.
2	INN	Inverting Input.
		Active-Low Enable Input. A logic low on this pin shuts down the device.
3	EN	Vss: device in shutdown.
		VDD: normal operation.
4	VDD	Positive Supply Input.
5	OUT	Amplifier Output.
6	VSS	Negative Supply Input. This pin must be connected to ground in single-supply applications.
7	SENSE	Sense Input. Ground this pin when external inverting gain control is required.
8	REF	Reference Input. Reference to non-inverting input resistor network.



5 Absolute Maximum Ratings

Stresses beyond those listed in Table 2 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in Electrical Characteristics on page 4 is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 2. Absolute Maximum Ratings

Parameter	Min	Max	Units	Comments
Electrical Parameters	•			
Supply Voltage (VDD to VSS)	-0.3	+7	V	
Supply Voltage (All Other Pins)	Vss - 0.3	VDD + 0.3	V	
Output Short-Circuit Duration to VDD or Vss		1	S	
Electrostatic Discharge	•			
Electrostatic Discharge HBM		1	kV	Norm: MIL 883 E method 3015
Temperature Ranges and Storage Conditions	•			
Thermal Resistance ⊕JA	33		°C/W	on PCB
Storage Temperature Range	-65	+150	ºC	
Junction Temperature		+150	ºC	
Package Body Temperature	+260		ºC	The reflow peak soldering temperature (body temperature) specified is in accordance with IPC/ JEDEC J-STD-020 "Moisture/Reflow Sensitivity Classification for Non-Hermetic Solid State Surface Mount Devices". The lead finish for Pb-free leaded packages is matte tin (100% Sn).
Humidity non-condensing	5	85	%	
Moisture Sensitive Level		1		Represents a max. floor life time of unlimited



6 Electrical Characteristics

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

DC Electrical Characteristics

VDD = 2.7V, VSS = 0V, VCM = VDD/2, VOUT = VDD/2, RLOAD = Infinite, VEN = VDD, Typical values at TAMB = 25° C (unless otherwise specified).

Table 3. DC Electrical Characteristics

Symbol	Parameter	Condition		Min	Тур	Max	Unit
Тамв	Operating Temperature Range			-40		+85	°C
VDD	Supply Voltage Range	Inferred from Power Supply Rejection Ratio Test		2.7		5.5	V
Voffset	Input Offset Voltage			-1.5		+1.5	mV
RSEIN	Single-Ended Input Resistance			8	10	12	kΩ
Vсм	Common Mode Input Voltage Range	Inferred from Common Mo	ode Rejection Ratio ¹	Vss		VDD	V
CMRR	Common Mode Rejection Ratio	Vss < Vcm	< VDD	45	60		dB
PSRR	Power Supply Rejection Ratio	VDD = 2.7 to	5.5V	60	70		dB
Rout	Shutdown Output Impedance	VEN = 0	V		130		Ω
Vout-shdnn	Shutdown Output Voltage	Ven = 0V, Rload =	= 2kΩ to VDD		170	400	mV
	Output Voltage Swing	., .,	RLOAD = 32Ω		350	650	mV
		VDD - VOH or VOL - VSS	RLOAD = 200Ω		70	120	
			RLOAD = $2k\Omega$		9	20	
Vout	Output Voltage	VDD - VOH or VOL - VSS	ILOAD = 10mA, VDD = 2.7V		55	100	mV
VOUT			ILOAD = 50mA, VDD = 5V		100	200	
lout	VDD = 2.7V, V- = VCM, V+ = VCM±100mV			100			
1001	Output Source/Sink Current	VDD = 5.0V, V- = VCM, V+ = VCM±100mV			200		- mA
lpp	Quiagaant Supply Current	VDD = 2.7V, VCM = VDD/2			1.6	3.2	mA
טטו	Quiescent Supply Current	VDD = 5.0V, VCM = VDD/2			2.3	4.6	IIIA
IDD-SHDNN	Shutdown Supply Current	VEN = 0V, VDD = 2.7V			1	2000 ¹	nA
	EN Logic Threshold	Shutdown Mode			Vss + 0.3		V
	LIN LOGIC THIESHOLD	Normal Operation			VDD - 0.3		
	EN Input Bias Current Vss < Ven < Vdd			50		pA	

^{1.} Guaranteed by design.



AC Electrical Characteristics

VDD = 2.7V, VSS = 0V, VCM = VDD/2, VOUT = VDD/2, RLOAD = Infinite, VEN = VDD, TAMB = -40 to $+85^{\circ}C$. Typical values at $TAMB = 25^{\circ}C$.

Table 4. AC Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
GBWP	Gain-Bandwidth Product	Vcm = Vdd/2		4		MHz	
f _C	Cut-off Frequency			8.5		MHz	
SR	Slew Rate			5		V/µs	
PM	Phase Margin			60		deg	
GM	Gain Margin ¹			10		dB	
THD+N	Total Harmonic Distortion Plus Noise	f = 10kHz, VOUT = 2VP-P, AVCL = 1V/V		60		dBc	
CIN	Input Capacitance			2		pF	
on	v., v. 51	f = 1kHz		40	n\//a/Li		
en	Voltage-Noise Density ¹	f = 10kHz		30		nV/√Hz	
	Capacitive-Load Stability	AVCL = 1V/V, no sustained oscillations		100		pF	
tshdn	Shutdown Time			1		μs	
tENABLE	Enable Time from Shutdown			7		μs	
ton	Power-Up Time			20		ns	

^{1.} Guaranteed by design.



7 Typical Operating Characteristics

VDD = 2.7V; VSS = 0V, VCM = VDD/2, VOUT = VDD/2, $RLOAD = \infty$, VEN = VDD $TAMB = +25^{\circ}C$ (unless otherwise specified).

Figure 3. Gain and Phase vs. Frequency

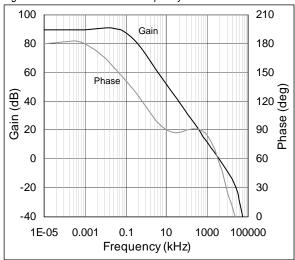


Figure 5. PSRR vs. Frequency

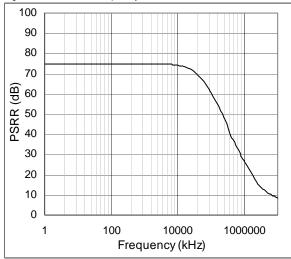


Figure 7. Supply Current vs. Temperature

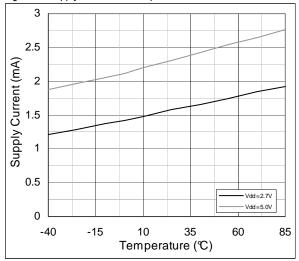


Figure 4. Gaind and Phase vs. freq.; CLOAD = 100pF

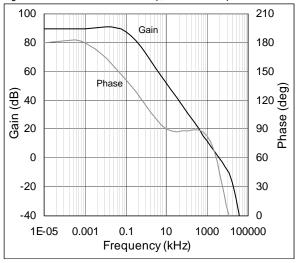


Figure 6. CMRR vs. Frequency

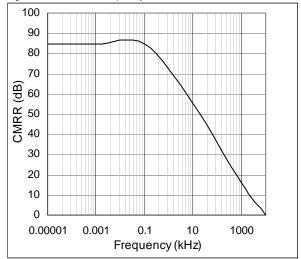


Figure 8. Shutdown Current vs. Temperature

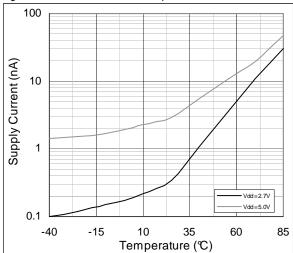




Figure 9. Supply Current vs. CMRR

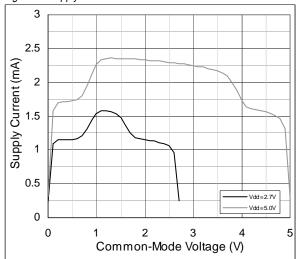


Figure 10. Input Voltage Noise vs. Frequency

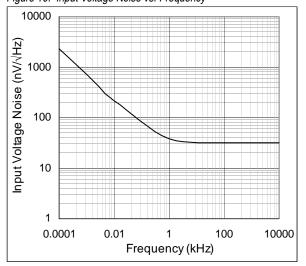


Figure 11. Output Swing High vs. Temp.; VDD = 2.7V

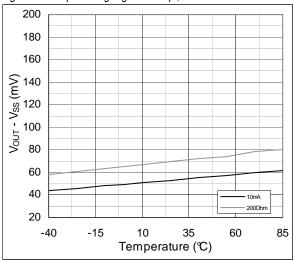


Figure 12. Output Swing Low vs. Temp.; VDD = 2.7V

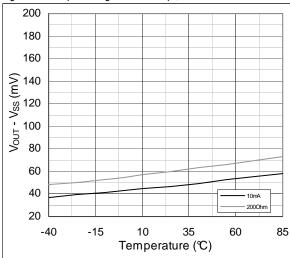


Figure 13. Output Swing High vs. Temp.; VDD = 5.5V

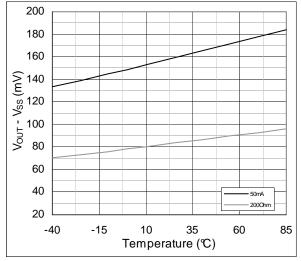


Figure 14. Output Swing Low vs. Temp.; VDD = 5.5V

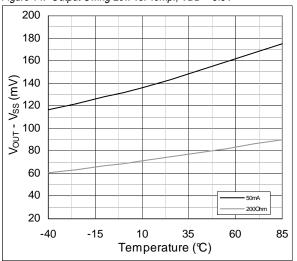




Figure 15. Vout vs. Iout, sourcing

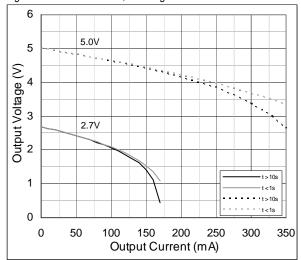


Figure 16. VOUT vs. IOUT, sinking

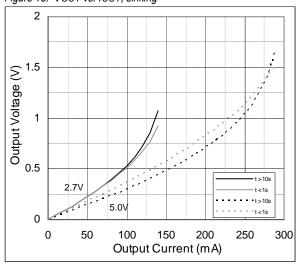


Figure 17. Transient Response; VIN = 100mV, CLOAD = 10pF

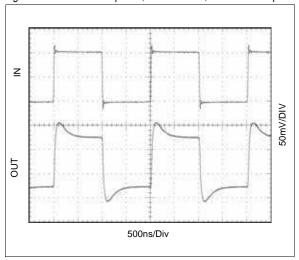


Figure 18. Transient Response; VIN = 100mV, CLOAD = 100pF

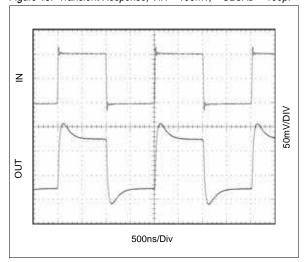


Figure 19. Transient Response; VIN = 1V, CLOAD = 10pF

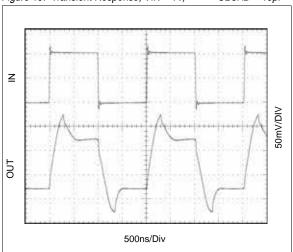


Figure 20. Transient Response; VIN = 1V, CLOAD = 100pF

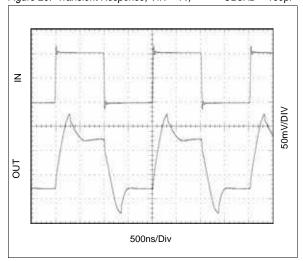
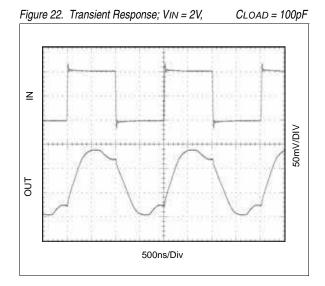




Figure 21. Transient Response; VIN = 2V, CLOAD = 10pF





8 Application Information

Ground Loop Interference Suppression:

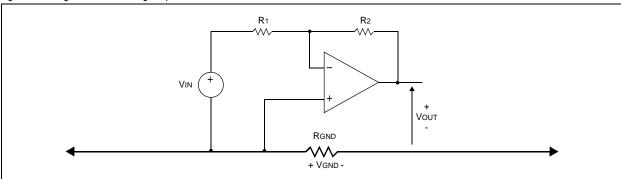
In real life situations the signal source and the amplifier are often located a distance apart, but still share the same ground arrangement with a number of other circuits. The ground system is never perfect as it has a small distributed resistance, capacitance and inductance. Thus, the ground appears as a distributed impedance.

As a various current flow into and out of the ground system exists, a small voltage drop will inevitably occur, causing different voltages within the ground. In Figure 23 and Figure 24, RGND denotes the ground resistance between the input signal ground and the output signal ground. The voltage drop across RGND should ideally have no effect on individual circuit performance.

In the single ended inverting amplifier shown in Figure 23, the amplifier sees VIN and VGND in series, so the amplifier output is:

$$VOUT = -[R_2/R_1][VIN+VGND]$$
 (EQ 1)

Figure 23. Single Ended Inverting Amplifier

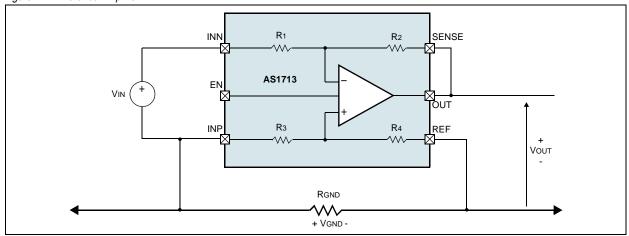


VGND is part of the output expression and is known as ground loop interference, ground bounce or even common impedance crosstalk. In some situations this interference signal can be close to or the same value as the wanted input signal such as in sensor applications.

A difference amplifier is a simple method used to reduce the effect of ground interference. VIN is regarded as a differential input signal, and VGND a common mode signal. From Figure 24, the amplifier output is:

$$VOUT = -[R_2/R_1] VIN$$
 (EQ 2)

Figure 24. Difference Amplifier

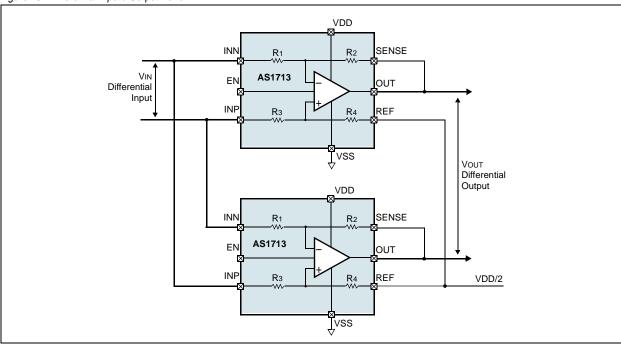


The additional cost of extra matched resistors is offset by the rejection of the unwanted common mode ground interference.



Differential Input / Output Buffer

Figure 25. Differential Input / Output Buffer



Rail-to-Rail Input Stage

The AS1713 CMOS op amps have parallel connected n- and p-channel differential input stages that combine to accept a common-mode range extending to both supply rails. The n-channel stage is active for common-mode input voltages typically greater than (Vss + 1.2V), and the p-channel stage is active for common-mode input voltages typically less than (VDD - 1.2V).

Rail-to-Rail Output Stage

The minimum output is within millivolts of ground for single- supply operation, where the load is referenced to ground (Vss). Figure 26 shows the input voltage range and the output voltage swing of an AS1713 connected as a voltage follower. The maximum output voltage swing is load dependent although it is guaranteed to be within 500mV of the positive rail (VDD = 2.7V) even with maximum load (32Ω to ground) as shown in Figure 27.

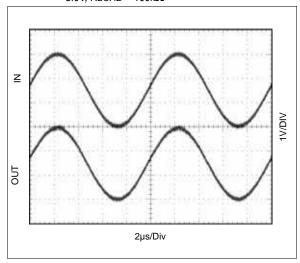


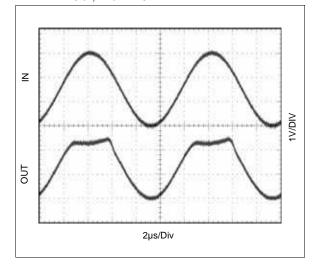
Figure 26. Rail-to-Rail Input / Output Range; 3.0V, RLOAD = $100k\Omega$

VIN = VDD =

Figure 27. Rail-to-Rail Input / Output Range; 3.0V, RLOAD = 32Ω

VIN = VDD =





Note: The absolute maximum ratings (see page 3) for power dissipation and output short-circuit duration (10s, max) must be adhered since the output current can exceed 200mA (see Typical Operating Characteristics on page 6).

Shutdown

When EN is pulled to low, the supply current drops to 0.5µA, the amplifier is disabled and the output is driven to Vss. Pulling EN to high enables the amplifier. When exiting shutdown, there is a 6µs delay before the amplifier output becomes active.

Note: Because the output is actively driven to Vss in shutdown, any pullup resistor on the output causes a current drain from the supply.

Power-Up

The AS1713 typically settle within 5µs after power-up.

Power Supplies and Layout

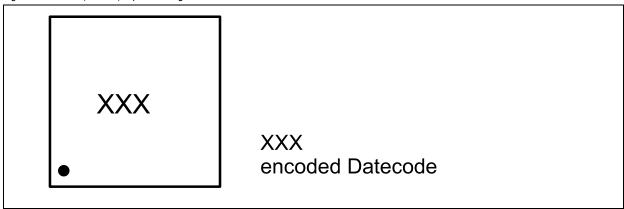
The AS1713 can operate from a single 2.7V to 5.5V supply or from dual ± 1.35 V to ± 2.5 V supplies. Good design improves device performance by decreasing the amount of stray capacitance at the op amp inputs/outputs.

- For single-supply operation, bypass the power supply with a 0.1µ F ceramic capacitor.
- For dual-supply operation, bypass each supply to ground.
- Decrease stray capacitance by placing external components close to the op amp pins, minimizing trace and lead lengths.

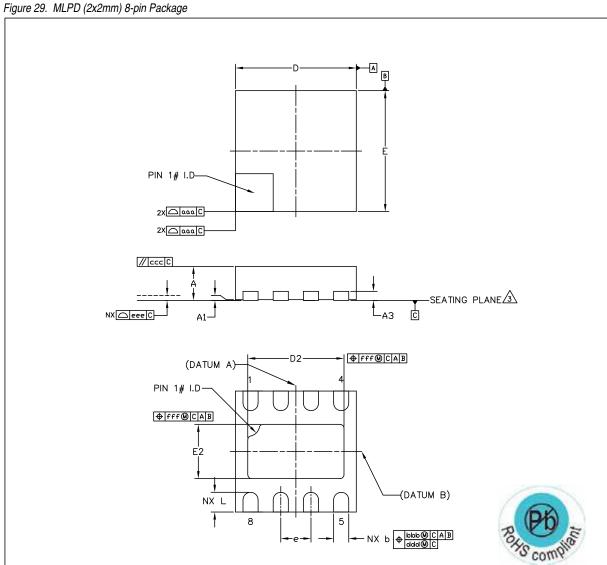


9 Package Drawings and Markings

Figure 28. MLPD (2x2mm) 8-pin Marking







DEE	1.711.1	11011	11111				
REF.	MIN	NOM	MAX				
Α	0.51	0.55	0.60				
A1	0.00	0.02	0.05				
A3		0.15 REF					
L	0.225	0.325	0.425				
b	0.18	0.25	0.425 0.30				
D		2.00 BSC					
E		2.00 BSC					
е		0.50 BSC					
D2	1.45	1.60	1.70				
E2	0.75	0.90	1.00				
aaa	_	0.15	_				
bbb	_	0.10	_				
ccc		0.10	_				
ddd	_	0.05	_				
eee	_	0.08	_				
fff	_	0.10	_				
N		8					

NOTE:

- 1. DIMENSIONS & TOLERANCEING CONFIRM TO ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGELS ARE IN DEGREES.
- COPLANARITY APPLIES TO THE EXPOSED HEAT SLUG AS WELL AS THE TERMINAL.
 - 4. RADIUS ON TERMINAL IS OPTIONAL.
 - 5. N IS THE TOTAL NUMBER OF TERMINALS.

aB austi	ria micro sy	stems	ASSEMBLY ENGINEERING	
DRAWN RH8	a leap ahead	rev. N/C	TITLE MLPD 2x2x0.55mm 8 LEAD, 1.60X0.90mm ePAD	REFERENCE DUCUMENT JEDEC MO - 248 LATEST REVISION
CHECKED GBO	DATE 2011.02.02		DRAVING NO. QFF	UNIT
APPROVED MKR	DATE 2011.02.02	SHEET 1 DF 1	DIMENSION AND TOLERANCE	SCALE NOT IN SCALE



10 Ordering Information

The device is available as the standard products shown in Table 5.

Table 5. Ordering Information

Ordering Code	Marking	Description	Delivery Form	Package
AS1713-BTDT	ABB	Difference Amplifier, 10MHz, 10V/µs, Rail-to-Rail I/O with Shutdown	Tape and Reel	MLPD (2x2mm) 8-pin

Note: All products are RoHS compliant.

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